

B320 - B360

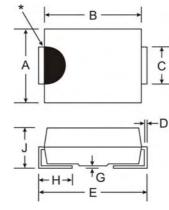
3.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- Guard Ring Die Construction for Transient Protection •
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 125A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- Lead Free Finish/RoHS Compliant (Note 4)

Mechanical Data

- Case: SMC •
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (C)
- Polarity: Cathode Band
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.21 grams (approximate)



SMC					
Dim	Min	Max			
Α	5.59	6.22			
в	6.60	7.11			
С	2.75	3.18			
D	0.15	0.31			
E	7.75	8.13			
G	0.10	0.20			
Н	0.76	1.52			
J	2.00	2.62			
All Dimensions in mm					

Note: Device may have a semicircular indentation/notch on one side of the device (as shown).

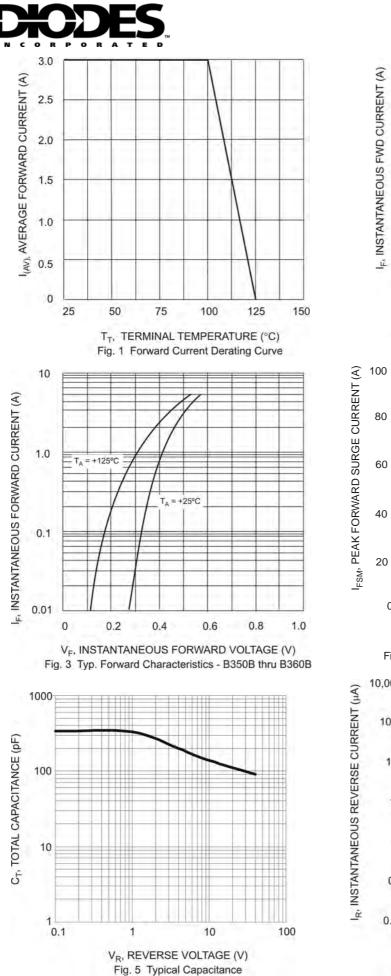
Maximum Ratings and Electrical Characteristics @T_A = 25°C unless otherwise specified

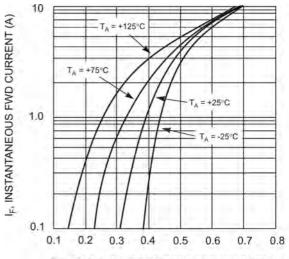
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

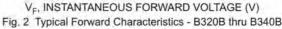
Characteristic	Symbol	B320	B330	B340	B350	B360	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	30	40	50	60	V
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	35	42	V
Average Rectified Output Current @ $T_T = 100C^{\circ}$	Ιo	3.0				Α	
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	1 125				A	
Forward Voltage (Note 3) $@$ I _F = 3.0A	V _{FM}	0.50 0.70		70	V		
Peak Reverse Current@ $T_A = 25^{\circ}C$ at Rated DC Blocking Voltage (Note 3)@ $T_A = 100^{\circ}C$	I _{RM}	0.5 20			mA		
Typical Capacitance (Note 2)	CT	200			pF		
Typical Thermal Resistance, Junction to Terminal	$R_{ ext{ heta}JT}$	20			°C/W		
Typical Thermal Resistance, Junction to Ambient (Note 1)	$R_{ ext{ heta}JA}$	90			°C/W		
Operating Temperature Range	Tj	-55 to +125			°C		
Storage Temperature Range	T _{STG}	-55 to +150			°C		

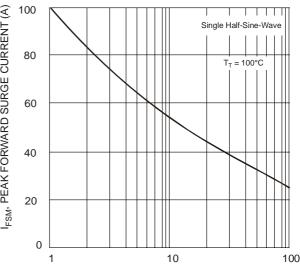
Notes:

- Thermal Resistance: Junction to terminal, unit mounted on glass epoxy substrate with 2x3mm copper pad Measured at 1.0MHz and applied reverse voltage of 4.0V DC. 1.
- 2.
- 3. 4.
- Short duration test pulse used to minimize self-heating effect. RoHS revision 13.2.2003. Glass and high temperature solder exemptions applied, see *EU Directive Annex Notes 5 and 7*.

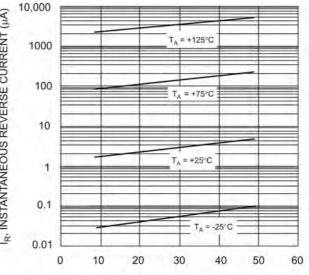








NUMBER OF CYCLES AT 60 Hz Fig. 4 Max Non-Repetitive Peak Forward Surge Current



V_R, INSTANTANEOUS REVERSE VOLTAGE (V) Fig. 6 Typical Reverse Characteristics, B320B thru B340B



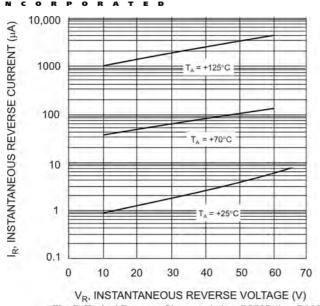


Fig. 7 Typical Reverse Characteristics, B350B thru B360B

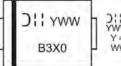
Ordering Information (Note 5)

Device*	Packaging	Shipping
B3x0-13-F	SMC	3000/Tape & Reel

* x = Device type, e.g. B320-13-F (SMC package).

Notes: 5. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information (Note 6)



Control Contro

Notes: 6. Device has a cathode band (as shown above) and may also have a cathode notch (as shown on Page 1).

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